








	<p><b>SQD50N04-09H-GE3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SQD50N04-09H-GE3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 40V 50A TO252</p> <p><b>Datenblätter:</b>  <a href="#">SQD50N04-09H-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 10194 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

**Spezifikationen**

Teilenummer	SQD50N04-09H-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 40V 50A TO252
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	10194 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	83W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	50A (Tc)
Rds On (Max) @ Id, Vgs	9 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	76nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4240pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Original-Reel®




































SQD50N04-09H-GE3 ist neu im Original, Suche SQD50N04-09H-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SQD50N04-09H-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SQD50N04-09H-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <b>SQD50N03-06P</b> V V TO-252	 <b>SQD50N04-09H-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 40V 50A TO252	 <b>SQD50N04-4M1</b> V SQD50N04-4M1 V	 <b>SQD50N04-4M5L-GE3</b> VISHAY VISHAY SO-252
 <b>SQD50N04-4M5L</b> VISHAY SQD50N04-4M5L VISHAY	 <b>SQD50N03-09-GE3</b> V SQD50N03-09-GE3 V	 <b>SQD50N03-06P-GE3</b> V SQD50N03-06P-GE3 V	 <b>SQD50N03-4M0L-GE3</b> V V TO-252

**heiße Teile**

Mehr

- |  |  |  |   |  |
|--|--|--|---|--|
|  SQD40N06-25L-GE3 |  SQD40N10-25      |  SQD40N10-25-GE3  |  SQD40P10-40L-GE3 |  SQD45N05-20L-GE3 |
|  SQD45N05-20L-GE3 |  SQD45P03-12      |  SQD45P03-12-GE3  |  SQD50A100        |  SQD50A60         |
|  SQD50A90         |  SQD50AA100       |  SQD50AB100       |  SQD50AB90        |  SQD50B90         |
|  SQD50BA100       |  SQD50BB75        |  SQD50BB90        |  SQD50CB100       |  SQD50DB100       |
|  SQD50N02-04-GE3  |  SQD50N03-06P-GE3 |  SQD50N03-09-GE3  |  SQD50N03-4M3     |  SQD50N04-09H-GE3 |
|  SQD50N04-3M5L    |  SQD50N04-4M1     |  SQD50N04-4M5L    |  SQD50N04-5M0-GE3 |  SQD50N04-5m6-GE3 |
|  SQD50N05-11      |  SQD50N05-11L     |  SQD50N05-11L-GE3 |  SQD50N06-092     |  SQD50N06-09L     |
|  SQD50N06-09L-GE3 |  SQD50N10-8m9L    |  SQD50P03-07-15   |  SQD50P03-07-GE3  |  SQD50P04-09L-GE3 |
|  SQD50P04-13L     |  SQD50P04-13L-GE3 |  SQD50P06-15L-GE3 |  SQD50P08-28      |  SQD65AB78        |
|  SQD65BA78        |  SQD65BB75        |  SQD70AA90        |  SQD70AB90        |  SQD70BB90        |

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